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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Active
Core Processor	R8C
Core Size	16-Bit
Speed	20MHz
Connectivity	I <sup>2</sup> C, LINbus, SIO, SSU, UART/USART
Peripherals	POR, PWM, Voltage Detect, WDT
Number of I/O	19
Program Memory Size	24KB (24K x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 8
RAM Size	2K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 5.5V
Data Converters	A/D 8x10b; D/A 2x8b
Oscillator Type	Internal
Operating Temperature	-20°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	24-WFQFN Exposed Pad
Supplier Device Package	24-HWQFN (4x4)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f213g5cnp-u0">https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f213g5cnp-u0</a>

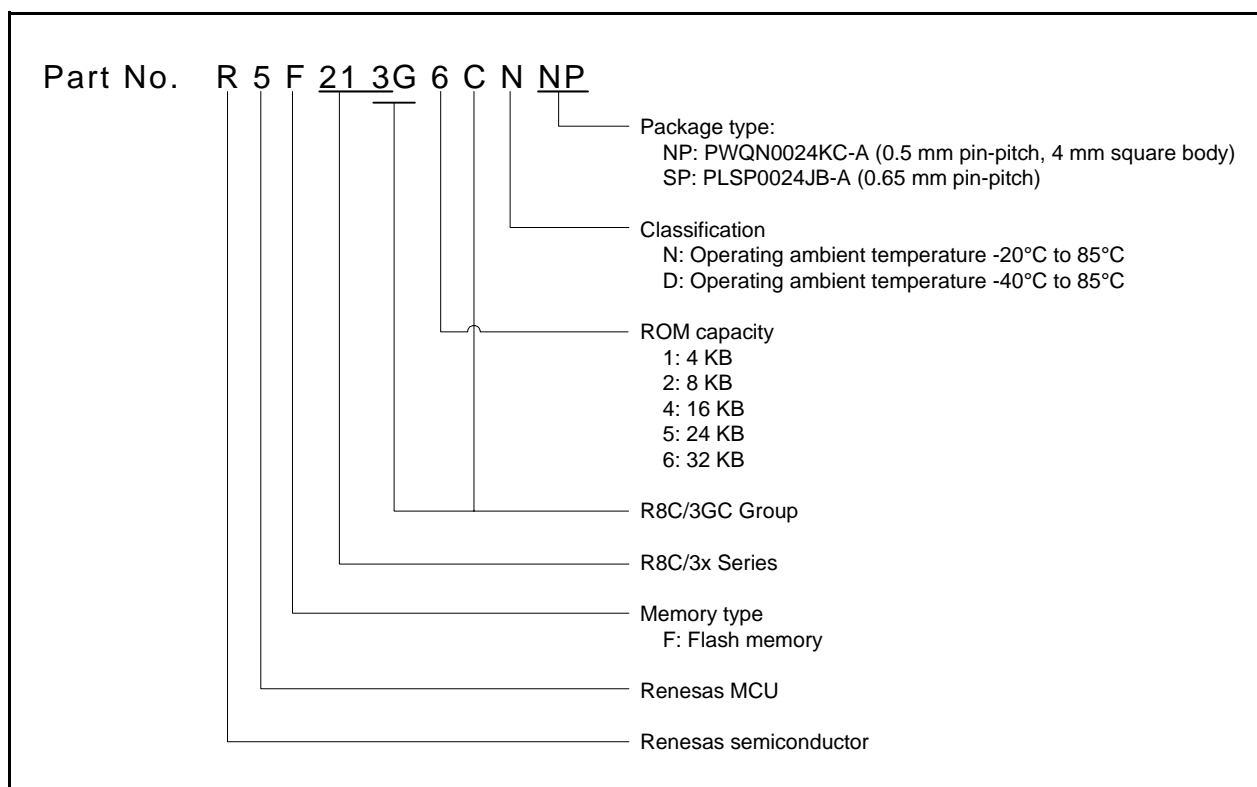
## 1.2 Product List

Table 1.3 lists Product List for R8C/3GC Group, and Figure 1.1 shows a Part Number, Memory Size, and Package of R8C/3GC Group.

**Table 1.3 Product List for R8C/3GC Group**

**Current of Oct 2010**

Part No.	ROM Capacity		RAM Capacity	Package Type	Remarks
	Program ROM	Data flash			
R5F213G2CNNP	8 Kbytes	1 Kbyte × 4	1 Kbyte	PWQN0024KC-A	N version
R5F213G4CNNP	16 Kbytes	1 Kbyte × 4	1.5 Kbytes	PWQN0024KC-A	
R5F213G5CNNP	24 Kbytes	1 Kbyte × 4	2 Kbytes	PWQN0024KC-A	
R5F213G6CNNP	32 Kbytes	1 Kbyte × 4	2.5 Kbytes	PWQN0024KC-A	
R5F213G1CNSP	4 Kbytes	1 Kbyte × 4	512 byte	PLSP0024JB-A	
R5F213G2CNSP	8 Kbytes	1 Kbyte × 4	1 Kbyte	PLSP0024JB-A	
R5F213G4CNSP	16 Kbytes	1 Kbyte × 4	1.5 Kbytes	PLSP0024JB-A	
R5F213G5CNSP	24 Kbytes	1 Kbyte × 4	2 Kbytes	PLSP0024JB-A	
R5F213G6CNSP	32 Kbytes	1 Kbyte × 4	2.5 Kbytes	PLSP0024JB-A	
R5F213G1CDSP	4 Kbytes	1 Kbyte × 4	512 byte	PLSP0024JB-A	D version
R5F213G2CDSP	8 Kbytes	1 Kbyte × 4	1 Kbyte	PLSP0024JB-A	
R5F213G4CDSP	16 Kbytes	1 Kbyte × 4	1.5 Kbytes	PLSP0024JB-A	
R5F213G5CDSP	24 Kbytes	1 Kbyte × 4	2 Kbytes	PLSP0024JB-A	
R5F213G6CDSP	32 Kbytes	1 Kbyte × 4	2.5 Kbytes	PLSP0024JB-A	



**Figure 1.1 Part Number, Memory Size, and Package of R8C/3GC Group**

## 2.1 Data Registers (R0, R1, R2, and R3)

R0 is a 16-bit register for transfer, arithmetic, and logic operations. The same applies to R1 to R3. R0 can be split into high-order bits (R0H) and low-order bits (R0L) to be used separately as 8-bit data registers. R1H and R1L are analogous to R0H and R0L. R2 can be combined with R0 and used as a 32-bit data register (R2R0). R3R1 is analogous to R2R0.

## 2.2 Address Registers (A0 and A1)

A0 is a 16-bit register for address register indirect addressing and address register relative addressing. It is also used for transfer, arithmetic, and logic operations. A1 is analogous to A0. A1 can be combined with A0 and as a 32-bit address register (A1A0).

## 2.3 Frame Base Register (FB)

FB is a 16-bit register for FB relative addressing.

## 2.4 Interrupt Table Register (INTB)

INTB is a 20-bit register that indicates the starting address of an interrupt vector table.

## 2.5 Program Counter (PC)

PC is 20 bits wide and indicates the address of the next instruction to be executed.

## 2.6 User Stack Pointer (USP) and Interrupt Stack Pointer (ISP)

The stack pointers (SP), USP and ISP, are each 16 bits wide. The U flag of FLG is used to switch between USP and ISP.

## 2.7 Static Base Register (SB)

SB is a 16-bit register for SB relative addressing.

## 2.8 Flag Register (FLG)

FLG is an 11-bit register indicating the CPU state.

### 2.8.1 Carry Flag (C)

The C flag retains carry, borrow, or shift-out bits that have been generated by the arithmetic and logic unit.

### 2.8.2 Debug Flag (D)

The D flag is for debugging only. Set it to 0.

### 2.8.3 Zero Flag (Z)

The Z flag is set to 1 when an arithmetic operation results in 0; otherwise to 0.

### 2.8.4 Sign Flag (S)

The S flag is set to 1 when an arithmetic operation results in a negative value; otherwise to 0.

### 2.8.5 Register Bank Select Flag (B)

Register bank 0 is selected when the B flag is 0. Register bank 1 is selected when this flag is set to 1.

### 2.8.6 Overflow Flag (O)

The O flag is set to 1 when an operation results in an overflow; otherwise to 0.

### 3. Memory

#### 3.1 R8C/3GC Group

Figure 3.1 is a Memory Map of R8C/3GC Group. The R8C/3GC Group has a 1-Mbyte address space from addresses 00000h to FFFFFh. The internal ROM (program ROM) is allocated lower addresses, beginning with address 0FFFFh. For example, a 32-Kbyte internal ROM area is allocated addresses 08000h to 0FFFFh.

The fixed interrupt vector table is allocated addresses 0FFDCh to 0FFFFh. The starting address of each interrupt routine is stored here.

The internal ROM (data flash) is allocated addresses 03000h to 03FFFh.

The internal RAM is allocated higher addresses, beginning with address 00400h. For example, a 2.5-Kbyte internal RAM area is allocated addresses 00400h to 00DFFh. The internal RAM is used not only for data storage but also as a stack area when a subroutine is called or when an interrupt request is acknowledged.

Special function registers (SFRs) are allocated addresses 00000h to 002FFh and 02C00h to 02FFFh. Peripheral function control registers are allocated here. All unallocated spaces within the SFRs are reserved and cannot be accessed by users.

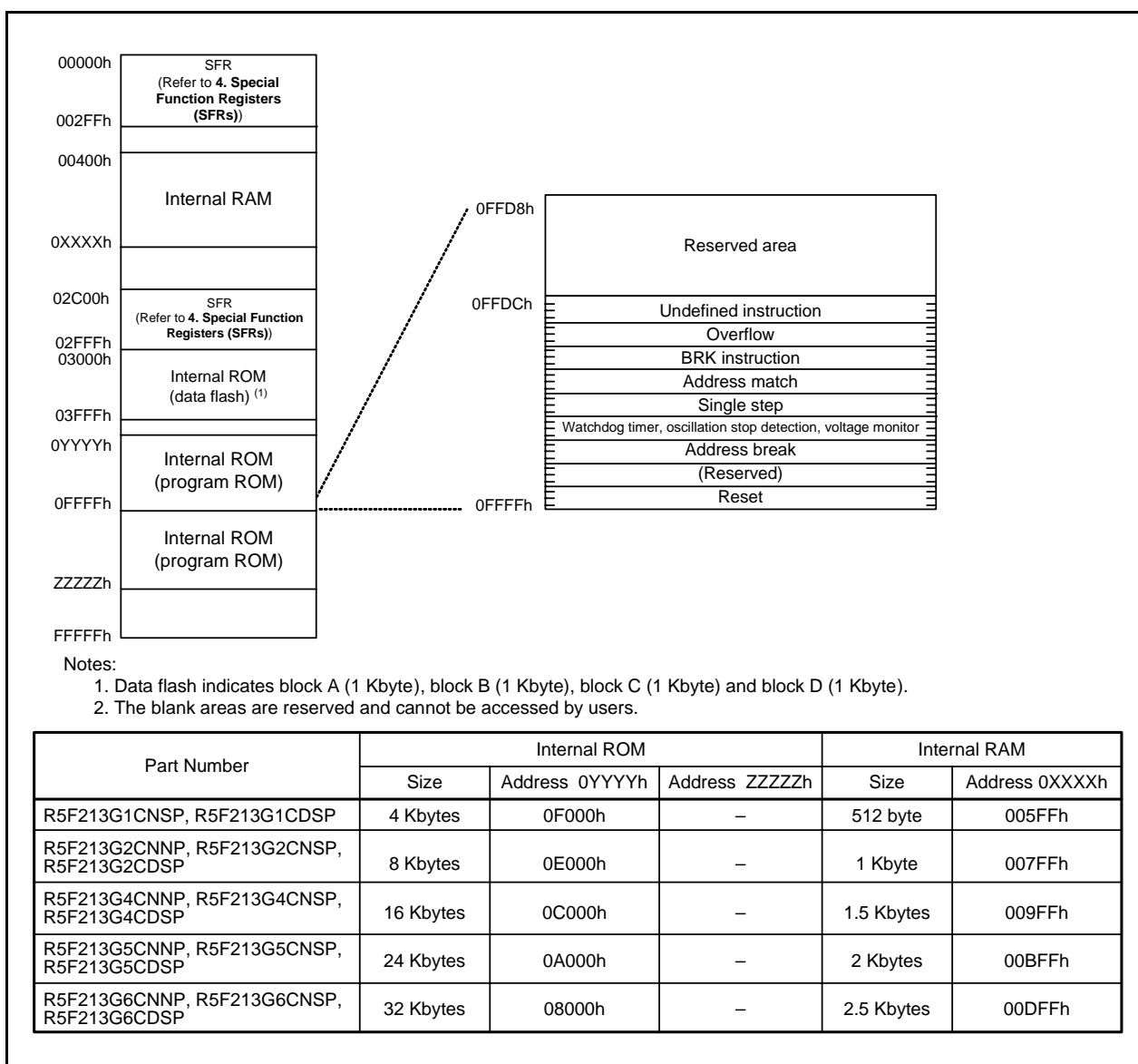


Figure 3.1 Memory Map of R8C/3GC Group

**Table 4.5 SFR Information (5) (1)**

Address	Register	Symbol	After Reset
0100h	Timer RA Control Register	TRACR	00h
0101h	Timer RA I/O Control Register	TRAIOC	00h
0102h	Timer RA Mode Register	TRAMR	00h
0103h	Timer RA Prescaler Register	TRAPRE	FFh
0104h	Timer RA Register	TRA	FFh
0105h	LIN Control Register 2	LINCR2	00h
0106h	LIN Control Register	LINCR	00h
0107h	LIN Status Register	LINST	00h
0108h	Timer RB Control Register	TRBCR	00h
0109h	Timer RB One-Shot Control Register	TRBOCR	00h
010Ah	Timer RB I/O Control Register	TRBIOC	00h
010Bh	Timer RB Mode Register	TRBMR	00h
010Ch	Timer RB Prescaler Register	TRBPRE	FFh
010Dh	Timer RB Secondary Register	TRBSC	FFh
010Eh	Timer RB Primary Register	TRBPR	FFh
010Fh			
0110h			
0111h			
0112h			
0113h			
0114h			
0115h			
0116h			
0117h			
0118h	Timer RE Second Data Register	TRESEC	00h
0119h	Timer RE Minute Data Register	TREMIN	00h
011Ah	Timer RE Hour Data Register	TREHR	00h
011Bh	Timer RE Day of Week Data Register	TREWK	00h
011Ch	Timer RE Control Register 1	TRECR1	00h
011Dh	Timer RE Control Register 2	TRECR2	00h
011Eh	Timer RE Count Source Select Register	TRECSR	00001000b
011Fh			
0120h	Timer RC Mode Register	TRCMR	01001000b
0121h	Timer RC Control Register 1	TRCCR1	00h
0122h	Timer RC Interrupt Enable Register	TRCIER	01110000b
0123h	Timer RC Status Register	TRCSR	01110000b
0124h	Timer RC I/O Control Register 0	TRCIOR0	10001000b
0125h	Timer RC I/O Control Register 1	TRCIOR1	10001000b
0126h	Timer RC Counter	TRC	00h
0127h			00h
0128h	Timer RC General Register A	TRCGRA	FFh
0129h			FFh
012Ah	Timer RC General Register B	TRCGRB	FFh
012Bh			FFh
012Ch	Timer RC General Register C	TRCGRC	FFh
012Dh			FFh
012Eh	Timer RC General Register D	TRCGRD	FFh
012Fh			FFh
0130h	Timer RC Control Register 2	TRCCR2	00011000b
0131h	Timer RC Digital Filter Function Select Register	TRCDF	00h
0132h	Timer RC Output Master Enable Register	TRCOER	01111111b
0133h	Timer RC Trigger Control Register	TRCADCR	00h
0134h			
0135h			
0136h			
0137h			
0138h			
0139h			
013Ah			
013Bh			
013Ch			
013Dh			
013Eh			
013Fh			

Note:

1. The blank areas are reserved and cannot be accessed by users.

**Table 4.8 SFR Information (8) (1)**

Address	Register	Symbol	After Reset
01C0h	Address Match Interrupt Register 0	RMAD0	XXh
01C1h			XXh
01C2h			0000XXXXb
01C3h	Address Match Interrupt Enable Register 0	AIER0	00h
01C4h	Address Match Interrupt Register 1	RMAD1	XXh
01C5h			XXh
01C6h			0000XXXXb
01C7h	Address Match Interrupt Enable Register 1	AIER1	00h
01C8h			
01C9h			
01CAh			
01CBh			
01CCh			
01CDh			
01CEh			
01CFh			
01D0h			
01D1h			
01D2h			
01D3h			
01D4h			
01D5h			
01D6h			
01D7h			
01D8h			
01D9h			
01DAh			
01DBh			
01DCh			
01DDh			
01DEh			
01DFh			
01E0h	Pull-Up Control Register 0	PUR0	00h
01E1h	Pull-Up Control Register 1	PUR1	00h
01E2h			
01E3h			
01E4h			
01E5h			
01E6h			
01E7h			
01E8h			
01E9h			
01EAh			
01EBh			
01ECh			
01EDh			
01EEh			
01EFh			
01F0h	Port P1 Drive Capacity Control Register	P1DRC	00h
01F1h			
01F2h	Drive Capacity Control Register 0	DRR0	00h
01F3h	Drive Capacity Control Register 1	DRR1	00h
01F4h			
01F5h	Input Threshold Control Register 0	VLT0	00h
01F6h	Input Threshold Control Register 1	VLT1	00h
01F7h			
01F8h	Comparator B Control Register 0	INTCMP	00h
01F9h			
01FAh	External Input Enable Register 0	INTEN	00h
01FBh			
01FCh	INT Input Filter Select Register 0	INTF	00h
01FDh			
01FEh	Key Input Enable Register 0	KIEN	00h
01FFh			

X: Undefined

Note:

- The blank areas are reserved and cannot be accessed by users.

**Table 4.9 SFR Information (9) (1)**

Address	Register	Symbol	After Reset
2C00h	DTC Transfer Vector Area		XXh
2C01h	DTC Transfer Vector Area		XXh
2C02h	DTC Transfer Vector Area		XXh
2C03h	DTC Transfer Vector Area		XXh
2C04h	DTC Transfer Vector Area		XXh
2C05h	DTC Transfer Vector Area		XXh
2C06h	DTC Transfer Vector Area		XXh
2C07h	DTC Transfer Vector Area		XXh
2C08h	DTC Transfer Vector Area		XXh
2C09h	DTC Transfer Vector Area		XXh
2C0Ah	DTC Transfer Vector Area		XXh
:	DTC Transfer Vector Area		XXh
:	DTC Transfer Vector Area		XXh
2C3Ah	DTC Transfer Vector Area		XXh
2C3Bh	DTC Transfer Vector Area		XXh
2C3Ch	DTC Transfer Vector Area		XXh
2C3Dh	DTC Transfer Vector Area		XXh
2C3Eh	DTC Transfer Vector Area		XXh
2C3Fh	DTC Transfer Vector Area		XXh
2C40h	DTC Control Data 0	DTCD0	XXh
2C41h			XXh
2C42h			XXh
2C43h			XXh
2C44h			XXh
2C45h			XXh
2C46h			XXh
2C47h			XXh
2C48h	DTC Control Data 1	DTCD1	XXh
2C49h			XXh
2C4Ah			XXh
2C4Bh			XXh
2C4Ch			XXh
2C4Dh			XXh
2C4Eh			XXh
2C4Fh			XXh
2C50h	DTC Control Data 2	DTCD2	XXh
2C51h			XXh
2C52h			XXh
2C53h			XXh
2C54h			XXh
2C55h			XXh
2C56h			XXh
2C57h			XXh
2C58h	DTC Control Data 3	DTCD3	XXh
2C59h			XXh
2C5Ah			XXh
2C5Bh			XXh
2C5Ch			XXh
2C5Dh			XXh
2C5Eh			XXh
2C5Fh			XXh
2C60h	DTC Control Data 4	DTCD4	XXh
2C61h			XXh
2C62h			XXh
2C63h			XXh
2C64h			XXh
2C65h			XXh
2C66h			XXh
2C67h			XXh
2C68h	DTC Control Data 5	DTCD5	XXh
2C69h			XXh
2C6Ah			XXh
2C6Bh			XXh
2C6Ch			XXh
2C6Dh			XXh
2C6Eh			XXh
2C6Fh			XXh

X: Undefined

Note:

1. The blank areas are reserved and cannot be accessed by users.

**Table 4.10 SFR Information (10) (1)**

Address	Register	Symbol	After Reset
2C70h	DTC Control Data 6	DTCD6	XXh
2C71h			XXh
2C72h			XXh
2C73h			XXh
2C74h			XXh
2C75h			XXh
2C76h			XXh
2C77h			XXh
2C78h	DTC Control Data 7	DTCD7	XXh
2C79h			XXh
2C7Ah			XXh
2C7Bh			XXh
2C7Ch			XXh
2C7Dh			XXh
2C7Eh			XXh
2C7Fh			XXh
2C80h	DTC Control Data 8	DTCD8	XXh
2C81h			XXh
2C82h			XXh
2C83h			XXh
2C84h			XXh
2C85h			XXh
2C86h			XXh
2C87h			XXh
2C88h	DTC Control Data 9	DTCD9	XXh
2C89h			XXh
2C8Ah			XXh
2C8Bh			XXh
2C8Ch			XXh
2C8Dh			XXh
2C8Eh			XXh
2C8Fh			XXh
2C90h	DTC Control Data 10	DTCD10	XXh
2C91h			XXh
2C92h			XXh
2C93h			XXh
2C94h			XXh
2C95h			XXh
2C96h			XXh
2C97h			XXh
2C98h	DTC Control Data 11	DTCD11	XXh
2C99h			XXh
2C9Ah			XXh
2C9Bh			XXh
2C9Ch			XXh
2C9Dh			XXh
2C9Eh			XXh
2C9Fh			XXh
2CA0h	DTC Control Data 12	DTCD12	XXh
2CA1h			XXh
2CA2h			XXh
2CA3h			XXh
2CA4h			XXh
2CA5h			XXh
2CA6h			XXh
2CA7h			XXh
2CA8h	DTC Control Data 13	DTCD13	XXh
2CA9h			XXh
2CAAh			XXh
2CABh			XXh
2CACH			XXh
2CADh			XXh
2CAEh			XXh
2CAFh			XXh

X: Undefined

Note:

1. The blank areas are reserved and cannot be accessed by users.



**Table 4.12 SFR Information (12) (1)**

Address	Register	Symbol	After Reset
2CF0h	DTC Control Data 22	DTCD22	XXh
2CF1h			XXh
2CF2h			XXh
2CF3h			XXh
2CF4h			XXh
2CF5h			XXh
2CF6h			XXh
2CF7h			XXh
2CF8h	DTC Control Data 23	DTCD23	XXh
2CF9h			XXh
2CFAh			XXh
2CFBh			XXh
2CFCh			XXh
2CFDh			XXh
2CFEh			XXh
2CFFh			XXh
2D00h			
⋮			
2FFh			

X: Undefined

Note:

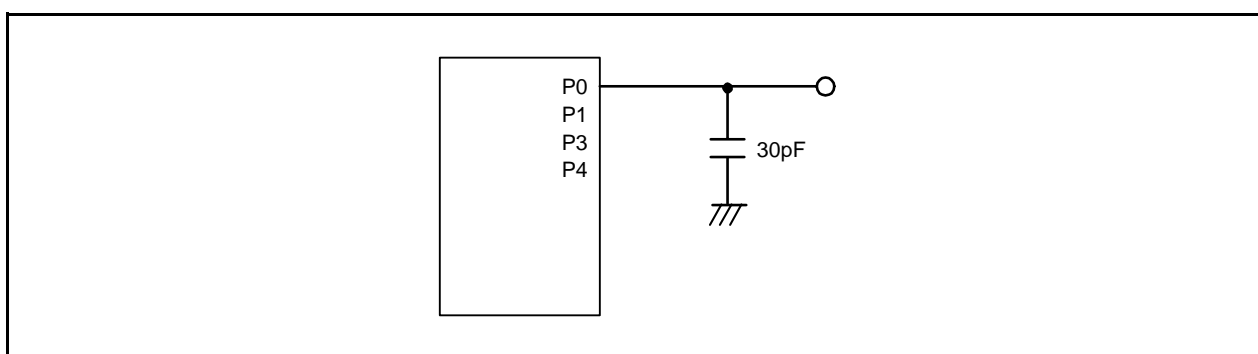
- The blank areas are reserved and cannot be accessed by users.

**Table 4.13 ID Code Areas and Option Function Select Area**

Address	Area Name	Symbol	After Reset
⋮			
FFDBh	Option Function Select Register 2	OFS2	(Note 1)
⋮			
FFDFh	ID1		(Note 2)
⋮			
FFE3h	ID2		(Note 2)
⋮			
FFEBh	ID3		(Note 2)
⋮			
FFEFh	ID4		(Note 2)
⋮			
FFF3h	ID5		(Note 2)
⋮			
FFF7h	ID6		(Note 2)
⋮			
FFFBh	ID7		(Note 2)
⋮			
FFFFh	Option Function Select Register	OFS	(Note 1)

Notes:

- The option function select area is allocated in the flash memory, not in the SFRs. Set appropriate values as ROM data by a program. Do not write additions to the option function select area. If the block including the option function select area is erased, the option function select area is set to FFh. When blank products are shipped, the option function select area is set to FFh. It is set to the written value after written by the user. When factory-programming products are shipped, the value of the option function select area is the value programmed by the user.
- The ID code areas are allocated in the flash memory, not in the SFRs. Set appropriate values as ROM data by a program. Do not write additions to the ID code areas. If the block including the ID code areas is erased, the ID code areas are set to FFh. When blank products are shipped, the ID code areas are set to FFh. They are set to the written value after written by the user. When factory-programming products are shipped, the value of the ID code areas is the value programmed by the user.



**Figure 5.1** Ports P0 to P1, P3 to P4 Timing Measurement Circuit

**Table 5.6 Flash Memory (Program ROM) Electrical Characteristics**

Symbol	Parameter	Conditions	Standard			Unit
			Min.	Typ.	Max.	
—	Program/erase endurance <sup>(2)</sup>		1,000 <sup>(3)</sup>	—	—	times
—	Byte program time		—	80	500	μs
—	Block erase time		—	0.3	—	s
t <sub>d</sub> (SR-SUS)	Time delay from suspend request until suspend		—	—	5+CPU clock × 3 cycles	ms
—	Interval from erase start/restart until following suspend request		0	—	—	μs
—	Time from suspend until erase restart		—	—	30+CPU clock × 1 cycle	μs
t <sub>d</sub> (CMDRST-READY)	Time from when command is forcibly terminated until reading is enabled		—	—	30+CPU clock × 1 cycle	μs
—	Program, erase voltage		2.7	—	5.5	V
—	Read voltage		1.8	—	5.5	V
—	Program, erase temperature		0	—	60	°C
—	Data hold time <sup>(7)</sup>	Ambient temperature = 55°C	20	—	—	year

**Notes:**

1. V<sub>CC</sub> = 2.7 to 5.5 V and T<sub>opr</sub> = 0 to 60°C, unless otherwise specified.

2. Definition of programming/erasure endurance

The programming and erasure endurance is defined on a per-block basis.

If the programming and erasure endurance is n (n = 1,000), each block can be erased n times. For example, if 1,024 1-byte writes are performed to different addresses in block A, a 1 Kbyte block, and then the block is erased, the programming/erasure endurance still stands at one.

However, the same address must not be programmed more than once per erase operation (overwriting prohibited).

3. Endurance to guarantee all electrical characteristics after program and erase. (1 to Min. value can be guaranteed).

4. In a system that executes multiple programming operations, the actual erasure count can be reduced by writing to sequential addresses in turn so that as much of the block as possible is used up before performing an erase operation. For example, when programming groups of 16 bytes, the effective number of rewrites can be minimized by programming up to 128 groups before erasing them all in one operation. It is also advisable to retain data on the erasure endurance of each block and limit the number of erase operations to a certain number.

5. If an error occurs during block erase, attempt to execute the clear status register command, then execute the block erase command at least three times until the erase error does not occur.

6. Customers desiring program/erase failure rate information should contact their Renesas technical support representative.

7. The data hold time includes time that the power supply is off or the clock is not supplied.

**Table 5.10 Voltage Detection 2 Circuit Electrical Characteristics**

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
V <sub>det2</sub>	Voltage detection level V <sub>det2_0</sub>	At the falling of V <sub>CC</sub>	3.70	4.00	4.30	V
—	Hysteresis width at the rising of V <sub>CC</sub> in voltage detection 2 circuit		—	0.10	—	V
—	Voltage detection 2 circuit response time <sup>(2)</sup>	At the falling of V <sub>CC</sub> from 5 V to (V <sub>det2_0</sub> – 0.1) V	—	20	150	μs
—	Voltage detection circuit self power consumption	VCA27 = 1, V <sub>CC</sub> = 5.0 V	—	1.7	—	μA
t <sub>d(E-A)</sub>	Waiting time until voltage detection circuit operation starts <sup>(3)</sup>		—	—	100	μs

Notes:

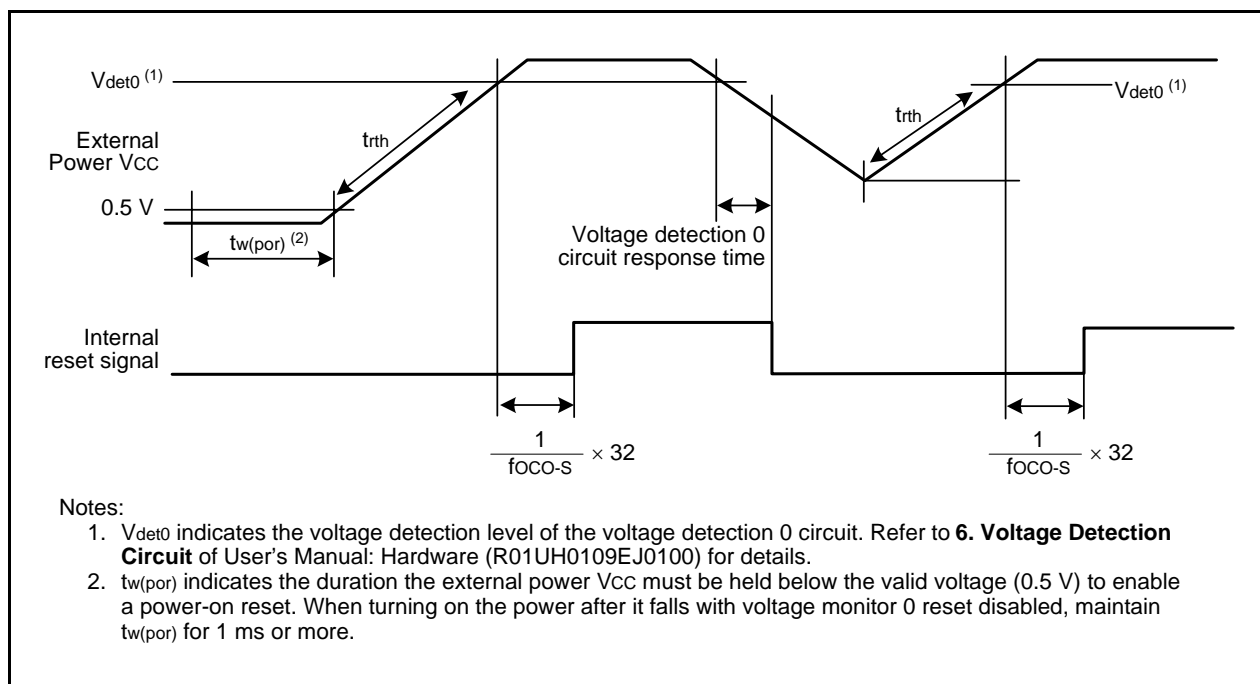
1. The measurement condition is V<sub>CC</sub> = 1.8 V to 5.5 V and T<sub>opr</sub> = –20 to 85°C (N version) / –40 to 85°C (D version).
2. Time until the voltage monitor 2 interrupt request is generated after the voltage passes V<sub>det2</sub>.
3. Necessary time until the voltage detection circuit operates after setting to 1 again after setting the VCA27 bit in the VCA2 register to 0.

**Table 5.11 Power-on Reset Circuit (2)**

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
t <sub>rth</sub>	External power V <sub>CC</sub> rise gradient	<sup>(1)</sup>	0	—	50,000	mV/msec

Notes:

1. The measurement condition is T<sub>opr</sub> = –20 to 85°C (N version) / –40 to 85°C (D version), unless otherwise specified.
2. To use the power-on reset function, enable voltage monitor 0 reset by setting the LVDAS bit in the OFS register to 0.

**Figure 5.3 Power-on Reset Circuit Electrical Characteristics**

**Table 5.15 Power Supply Circuit Timing Characteristics**

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
t <sub>d(P-R)</sub>	Time for internal power supply stabilization during power-on <sup>(2)</sup>		—	—	2,000	μs

Notes:

1. The measurement condition is V<sub>CC</sub> = 1.8 to 5.5 V and T<sub>opr</sub> = 25°C.
2. Waiting time until the internal power supply generation circuit stabilizes during power-on.

**Table 5.16 Timing Requirements of Synchronous Serial Communication Unit (SSU) <sup>(1)</sup>**

Symbol	Parameter		Conditions	Standard			Unit
				Min.	Typ.	Max.	
t <sub>SUCYC</sub>	SSCK clock cycle time			4	—	—	t <sub>CYC</sub> <sup>(2)</sup>
t <sub>HI</sub>	SSCK clock "H" width			0.4	—	0.6	t <sub>SUCYC</sub>
t <sub>LO</sub>	SSCK clock "L" width			0.4	—	0.6	t <sub>SUCYC</sub>
t <sub>RISE</sub>	SSCK clock rising time	Master		—	—	1	t <sub>CYC</sub> <sup>(2)</sup>
		Slave		—	—	1	μs
t <sub>FALL</sub>	SSCK clock falling time	Master		—	—	1	t <sub>CYC</sub> <sup>(2)</sup>
		Slave		—	—	1	μs
t <sub>SU</sub>	SSO, SSI data input setup time			100	—	—	ns
t <sub>H</sub>	SSO, SSI data input hold time			1	—	—	t <sub>CYC</sub> <sup>(2)</sup>
t <sub>LEAD</sub>	$\overline{\text{SCS}}$ setup time	Slave		1t <sub>CYC</sub> + 50	—	—	ns
t <sub>LAG</sub>	$\overline{\text{SCS}}$ hold time	Slave		1t <sub>CYC</sub> + 50	—	—	ns
t <sub>OD</sub>	SSO, SSI data output delay time			—	—	1	t <sub>CYC</sub> <sup>(2)</sup>
t <sub>SA</sub>	SSI slave access time		2.7 V ≤ V <sub>CC</sub> ≤ 5.5 V	—	—	1.5t <sub>CYC</sub> + 100	ns
			1.8 V ≤ V <sub>CC</sub> < 2.7 V	—	—	1.5t <sub>CYC</sub> + 200	ns
t <sub>OR</sub>	SSI slave out open time		2.7 V ≤ V <sub>CC</sub> ≤ 5.5 V	—	—	1.5t <sub>CYC</sub> + 100	ns
			1.8 V ≤ V <sub>CC</sub> < 2.7 V	—	—	1.5t <sub>CYC</sub> + 200	ns

Notes:

1. V<sub>CC</sub> = 1.8 to 5.5 V, V<sub>SS</sub> = 0 V and T<sub>opr</sub> = −20 to 85°C (N version) / −40 to 85°C (D version), unless otherwise specified.
2. 1t<sub>CYC</sub> = 1/f<sub>1</sub>(s)

**Table 5.19 Electrical Characteristics (2) [ $3.3\text{ V} \leq V_{CC} \leq 5.5\text{ V}$ ]**  
**( $T_{opr} = -20\text{ to }85^{\circ}\text{C}$  (N version) /  $-40\text{ to }85^{\circ}\text{C}$  (D version), unless otherwise specified.)**

Symbol	Parameter	Condition		Standard			Unit
				Min.	Typ.	Max.	
Icc	Power supply current (Vcc = 3.3 to 5.5 V) Single-chip mode, output pins are open, other pins are Vss	High-speed clock mode	XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	–	6.5	15	mA
			XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	–	5.3	12.5	mA
			XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	–	3.6	–	mA
			XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	3.0	–	mA
			XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	2.2	–	mA
			XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	1.5	–	mA
		High-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator on fOCO-F = 20 MHz Low-speed on-chip oscillator on = 125 kHz No division	–	7.0	15	mA
			XIN clock off High-speed on-chip oscillator on fOCO-F = 20 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	3.0	–	mA
			XIN clock off High-speed on-chip oscillator on fOCO-F = 4 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-16, MSTIC = MSTTRD = MSTTRC = 1	–	1	–	mA
		Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR27 = 1, VCA20 = 0	–	90	400	μA
		Low-speed clock mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz No division, FMR27 = 1, VCA20 = 0	–	85	400	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz No division, Program operation on RAM Flash memory off, FMSTP = 1, VCA20 = 0	–	47	–	μA
		Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	–	15	100	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	–	4	90	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (peripheral clock off) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	–	3.5	–	μA
		Stop mode	XIN clock off, Topr = 25°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1, Peripheral clock off VCA27 = VCA26 = VCA25 = 0	–	2.0	5.0	μA
			XIN clock off, Topr = 85°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1, Peripheral clock off VCA27 = VCA26 = VCA25 = 0	–	5.0	–	μA

**Table 5.24 Electrical Characteristics (3) [ $2.7\text{ V} \leq V_{CC} < 4.2\text{ V}$ ]**

Symbol	Parameter		Condition		Standard			Unit
					Min.	Typ.	Max.	
VOH	Output “H” voltage	Other than XOUT	Drive capacity High	IOH = −5 mA	VCC − 0.5	−	VCC	V
			Drive capacity Low	IOH = −1 mA	VCC − 0.5	−	VCC	V
		XOUT		IOH = −200 μA	1.0	−	VCC	V
VOL	Output “L” voltage	Other than XOUT	Drive capacity High	IOL = 5 mA	−	−	0.5	V
			Drive capacity Low	IOL = 1 mA	−	−	0.5	V
		XOUT		IOL = 200 μA	−	−	0.5	V
VT+·VT-	Hysteresis	INT0, INT1, INT3, KI0, KI1, KI2, KI3, TRAIO, TRBO, TRCIOA, TRCIOB, TRCIOC, TRCIOD, TRCTRIG, TRCCLK, ADTRG, RXD0, RXD2, CLK0, CLK2, SSI, SCL, SDA, SSO	VCC = 3.0 V		0.1	0.4	−	V
		RESET	VCC = 3.0 V		0.1	0.5	−	V
IiH	Input “H” current		VI = 3 V, VCC = 3.0 V		−	−	4.0	μA
IiL	Input “L” current		VI = 0 V, VCC = 3.0 V		−	−	−4.0	μA
RPULLUP	Pull-up resistance		VI = 0 V, VCC = 3.0 V		42	84	168	kΩ
RfXIN	Feedback resistance	XIN			−	0.3	−	MΩ
RfXCIN	Feedback resistance	XCIN			−	8	−	MΩ
VRAM	RAM hold voltage		During stop mode		1.8	−	−	V

Note:

1.  $2.7\text{ V} \leq V_{CC} < 4.2\text{ V}$  and  $T_{opr} = -20\text{ to }85^{\circ}\text{C}$  (N version) /  $-40\text{ to }85^{\circ}\text{C}$  (D version),  $f(XIN) = 10\text{ MHz}$ , unless otherwise specified.

**Table 5.25 Electrical Characteristics (4) [ $2.7\text{ V} \leq V_{CC} < 3.3\text{ V}$ ]**  
**( $T_{opr} = -20\text{ to }85^{\circ}\text{C}$  (N version) /  $-40\text{ to }85^{\circ}\text{C}$  (D version), unless otherwise specified.)**

Symbol	Parameter	Condition	Standard			Unit	
			Min.	Typ.	Max.		
Icc	Power supply current (Vcc = 2.7 to 3.3 V) Single-chip mode, output pins are open, other pins are Vss	High-speed clock mode	XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	–	3.5	10	mA
			XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	1.5	7.5	mA
		High-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator on fOCO-F = 20 MHz Low-speed on-chip oscillator on = 125 kHz No division	–	7.0	15	mA
			XIN clock off High-speed on-chip oscillator on fOCO-F = 20 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	3.0	–	mA
			XIN clock off High-speed on-chip oscillator on fOCO-F = 10 MHz Low-speed on-chip oscillator on = 125 kHz No division	–	4.0	–	mA
			XIN clock off High-speed on-chip oscillator on fOCO-F = 10 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	1.5	–	mA
			XIN clock off High-speed on-chip oscillator on fOCO-F = 4 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-16 MSTIIC = MSTTRD = MSTTRC = 1	–	1	–	mA
			Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR27 = 1, VCA20 = 0	–	90	390
		Low-speed clock mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz No division, FMR27 = 1, VCA20 = 0	–	80	400	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz No division, Program operation on RAM Flash memory off, FMSTP = 1, VCA20 = 0	–	40	–	μA
		Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0, VCA20 = 1	–	15	90	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0, VCA20 = 1	–	4	80	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (peripheral clock off) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0, VCA20 = 1	–	3.5	–	μA
		Stop mode	XIN clock off, Topr = 25°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	–	2.0	5.0	μA
			XIN clock off, Topr = 85°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	–	5.0	–	μA



**Table 5.30 Electrical Characteristics (5) [ $1.8\text{ V} \leq V_{CC} < 2.7\text{ V}$ ]**

Symbol	Parameter		Condition		Standard			Unit
					Min.	Typ.	Max.	
V <sub>OH</sub>	Output "H" voltage	Other than XOUT	Drive capacity High	I <sub>OH</sub> = -2 mA	V <sub>CC</sub> - 0.5	—	V <sub>CC</sub>	V
			Drive capacity Low	I <sub>OH</sub> = -1 mA	V <sub>CC</sub> - 0.5	—	V <sub>CC</sub>	V
		XOUT		I <sub>OH</sub> = -200 $\mu$ A	1.0	—	V <sub>CC</sub>	V
V <sub>OL</sub>	Output "L" voltage	Other than XOUT	Drive capacity High	I <sub>OL</sub> = 2 mA	—	—	0.5	V
			Drive capacity Low	I <sub>OL</sub> = 1 mA	—	—	0.5	V
		XOUT		I <sub>OL</sub> = 200 $\mu$ A	—	—	0.5	V
V <sub>T+</sub> -V <sub>T-</sub>	Hysteresis	INT0, INT1, INT3, KI0, KI1, KI2, KI3, TRAIO, TRBO, TRCIOA, TRCIOB, TRCIOA, TRCIOB, TRCIOA, TRCIOB, TRCIOA, TRCIOB, TRCIOA, TRCIOB, ADTRG, RXD0, RXD2, CLK0, CLK2, SSI, SCL, SDA, SSO			0.05	0.2	—	V
		RESET			0.05	0.20	—	V
I <sub>IH</sub>	Input "H" current		V <sub>I</sub> = 2.2 V, V <sub>CC</sub> = 2.2 V		—	—	4.0	$\mu$ A
I <sub>IL</sub>	Input "L" current		V <sub>I</sub> = 0 V, V <sub>CC</sub> = 2.2 V		—	—	-4.0	$\mu$ A
R <sub>PULLUP</sub>	Pull-up resistance		V <sub>I</sub> = 0 V, V <sub>CC</sub> = 2.2 V		70	140	300	k $\Omega$
R <sub>FXIN</sub>	Feedback resistance	XIN			—	0.3	—	M $\Omega$
R <sub>FXCIN</sub>	Feedback resistance	XCIN			—	8	—	M $\Omega$
V <sub>RAM</sub>	RAM hold voltage		During stop mode		1.8	—	—	V

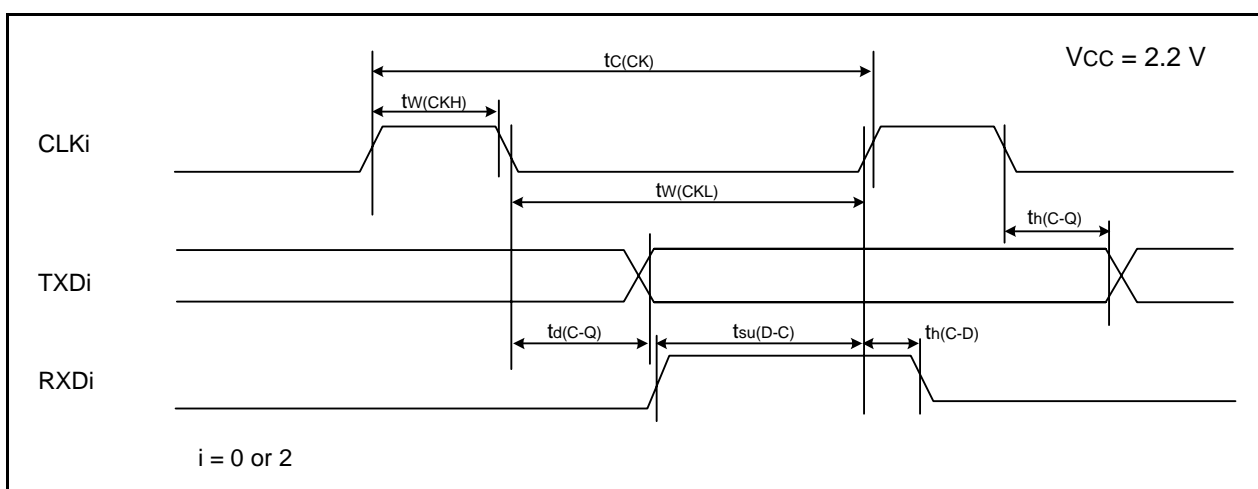
Note:

1.  $1.8\text{ V} \leq V_{CC} < 2.7\text{ V}$  and T<sub>opr</sub> = -20 to 85°C (N version) / -40 to 85°C (D version), f(XIN) = 5 MHz, unless otherwise specified.

**Table 5.34 Serial Interface**

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(CK)}$	CLKi input cycle time	800	—	ns
$t_{w(CKH)}$	CLKi input "H" width	400	—	ns
$t_{w(CKL)}$	CLKi input "L" width	400	—	ns
$t_{d(C-Q)}$	TXDi output delay time	—	200	ns
$t_{h(C-Q)}$	TXDi hold time	0	—	ns
$t_{su(D-C)}$	RXDi input setup time	150	—	ns
$t_{h(C-D)}$	RXDi input hold time	90	—	ns

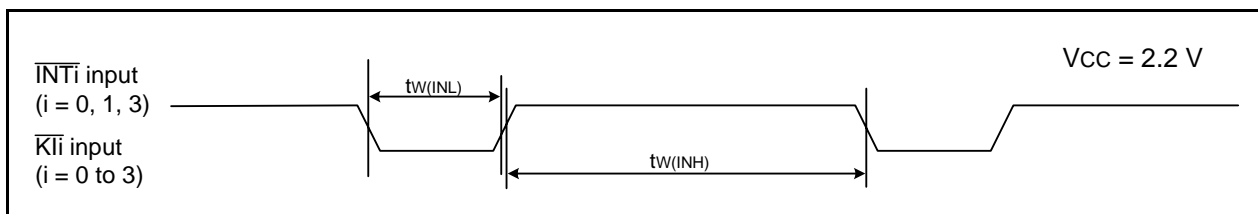
i = 0 or 2

**Figure 5.18 Serial Interface Timing Diagram when Vcc = 2.2 V****Table 5.35 External Interrupt  $\overline{INTi}$  (i = 0, 1, 3) Input, Key Input Interrupt  $\overline{Kli}$  (i = 0 to 3)**

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{w(INH)}$	$\overline{INTi}$ input "H" width, $\overline{Kli}$ input "H" width	1000 (1)	—	ns
$t_{w(INL)}$	$\overline{INTi}$ input "L" width, $\overline{Kli}$ input "L" width	1000 (2)	—	ns

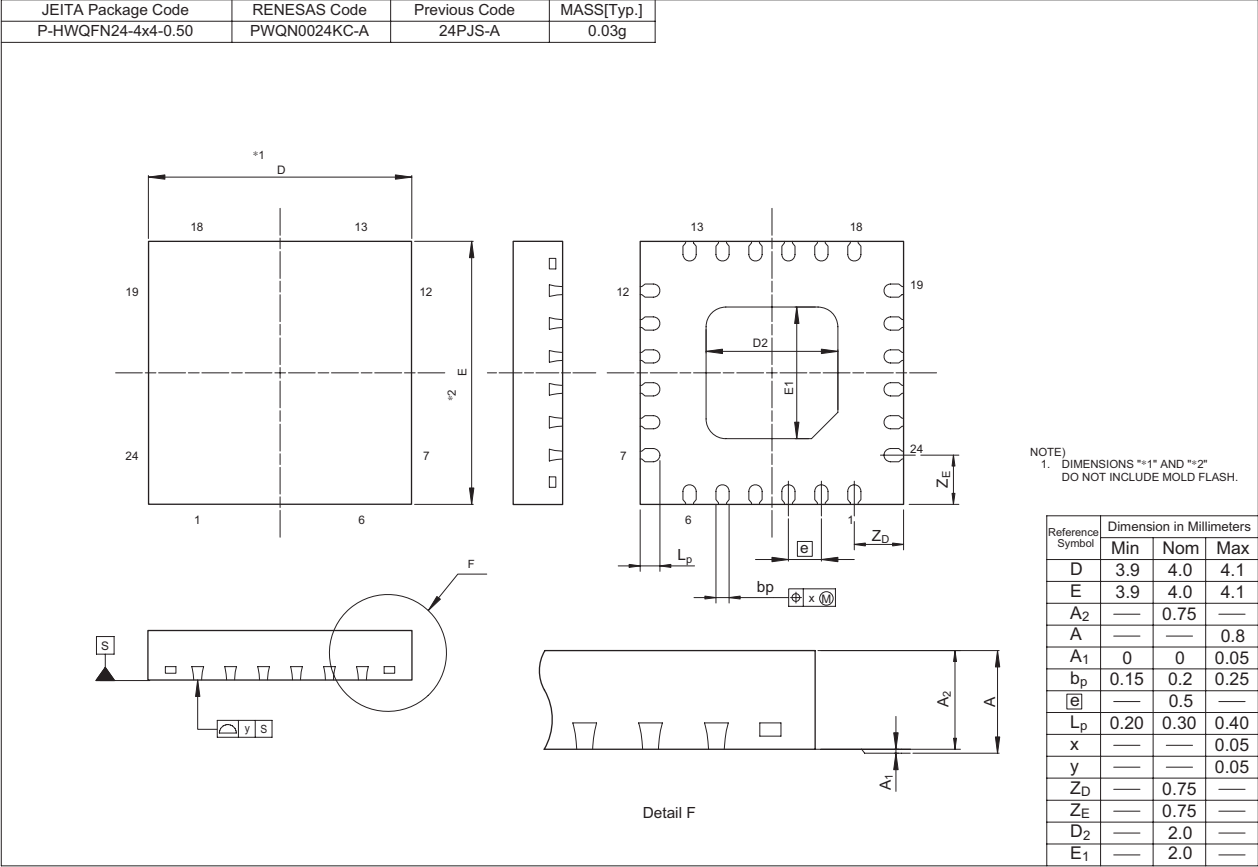
Notes:

- When selecting the digital filter by the  $\overline{INTi}$  input filter select bit, use an  $\overline{INTi}$  input HIGH width of either (1/digital filter clock frequency  $\times$  3) or the minimum value of standard, whichever is greater.
- When selecting the digital filter by the  $\overline{INTi}$  input filter select bit, use an  $\overline{INTi}$  input LOW width of either (1/digital filter clock frequency  $\times$  3) or the minimum value of standard, whichever is greater.

**Figure 5.19 Input Timing Diagram for External Interrupt  $\overline{INTi}$  and Key Input Interrupt  $\overline{Kli}$  when Vcc = 2.2 V**

Package Dimensions

Diagrams showing the latest package dimensions and mounting information are available in the “Packages” section of the Renesas Electronics website.



REVISION HISTORY	R8C/3GC Group Datasheet
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Rev.	Date	Description	
		Page	Summary
0.01	Oct. 30, 2009	—	First Edition issued
0.10	May 24, 2010	10	Table 1.6 XOUT: I → I/O
		28 to 54	"5. Electrical Characteristics" added
		55, 56	"Package Dimensions" revised
1.00	Oct 19, 2010	All	"Under development" deleted
		4	Table 1.3 QFN: D version deleted
		15	Figure 3.1 QFN: D version deleted
		31	Table 32.3 "tCONV", "tSAMP" revised
		37	Table 32.12 added, Table 32.13 revised

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1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada  
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Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.  
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Tel: +49-211-65030, Fax: +49-211-6503-1327

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